NSN 5961-01-121-0300

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-121-0300 **Inclosure Material:** Metal **Overall Length:** 0.792 inches **Overall Diameter:** 0.240 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 reverse voltage, instantaneous **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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